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U.S. PATENT DOCUMENTS														
Examiner Initial	Document Number			Date			Name		Class	Subclass	Filing Date if Appropriate			
	JP	7	-	1	5	4	0	2	3	6-16-1995	Japan		Abstract	
	JP	7	-	2	4	0	3	7	3	9-12-1995	Japan		Abstract	
	JP	8	-	2	2	2	7	6	4	8-30-1996	Japan		Abstract	
FOREIGN PATENT DOCUMENTS														
	Document Number							Date	Country	Class	Subclass	Translation		
	JP	7	-	1	5	4	0	2	3	6-16-1995	Japan		Yes	No
	JP	7	-	2	4	0	3	7	3	9-12-1995	Japan		Yes	No
	JP	8	-	2	2	2	7	6	4	8-30-1996	Japan		Yes	No
Alloy Semiconductor Physics and Electronics Symposium, pgs. 337-340 N. Ohkouchi, et al. (July 1993) "MOVPE Growth of GaAs _{1-x} N _x Alloys", Twelfth Record of														
EXAMINER <i>hanna Schuf</i>				DATE CONSIDERED <i>6/8/07</i>										

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